NSN 5961-00-068-6824

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-068-6824 **Inclosure Material:** Metal **Overall Length:** 1.180 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 2.00 amperes gate current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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